
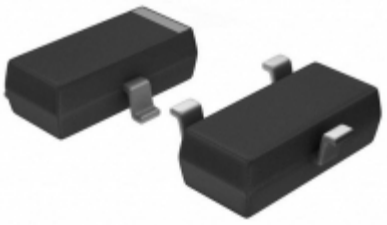
	<p>SI2321DS-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI2321DS-T1-GE3</p> <hr/> <p>Hersteller / Marke: Vishay / Siliconix</p> <hr/> <p>Teil der Beschreibung: MOSFET P-CH 20V 2.9A SOT-23</p> <hr/> <p>Datenblätter:  SI2321DS-T1-GE3.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 46496 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI2321DS-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 20V 2.9A SOT-23
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	46496 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	710mW (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	2.9A (Ta)
Rds On (Max) @ Id, Vgs	57 mOhm @ 3.3A, 4.5V
VGS (th) (Max) @ Id	900mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	13nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	715pF @ 6V
Verpackung	Tape & Reel (TR)





















SI2321DS-T1-GE3 ist neu im Original, Suche SI2321DS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2321DS-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI2321DS-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI2321-TP Micro Commercial Components (MCC) P-CHANNEL MOSFET, SOT-23 PACKAGE</p>	 <p>SI2323CDS-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 6A SOT-23</p>	 <p>SI2323CDS-T1-E3 VISHAY SI2323CDS-T1-E3 VISHAY</p>	 <p>SI2321DS-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 2.9A SOT-23</p>
 <p>SI2321DS-T1-E3 Vishay / Siliconix MOSFET P-CH 20V 2.9A SOT-23</p>	 <p>SI2321DS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 2.9A SOT-23</p>	 <p>SI2321DS 89K SI2321DS 89K</p>	 <p>SI2321/CJ2321 Original SOT-23</p>

heiße Teile

Mehr

- | | | | | |
|--|--|--|---|--|
|  SI2318BDS-T1-GE3 |  SI2318CDS-T1-E3 |  SI2318CDS-T1-GE3 |  SI2318CDS-T1-GE3 |  SI2318DS |
|  SI2318DS-T1-E3 |  SI2318DS-T1-E3 |  SI2318DS-T1-GE3 |  SI2318DS-T1-GE3 |  SI2319ADS-T1-GE3 |
|  SI2319C95TF |  SI2319CDS-T1-E3 |  SI2319CDS-T1-GE3 |  SI2319CDS-T1-GE3 |  SI2319DDS-T1-GE3 |
|  SI2319DS |  SI2319DS-T1-E3 |  SI2319DS-T1-E3 |  SI2319DS-T1-GE3 |  SI2319DS-T1-GE3 |
|  SI2320DS |  SI2320DS-T1-E3 |  SI2320DS-T1-GE3 |  SI2321DS-T1-E3 |  SI2321DS-T1-E3 |
|  SI2321DS-T1-GE3 |  SI2323CDS-T1 |  SI2323CDS-T1-E3 |  SI2323CDS-T1-GE3 |  SI2323CDS-T1-GE3 |
|  SI2323DDS-T1-E3 |  SI2323DDS-T1-GE3 |  SI2323DDS-T1-GE3 |  SI2323DS |  SI2323DS-T1-E3 |
|  SI2323DS-T1-E3 |  SI2323DS-T1-GE3 |  SI2323DS-T1-GE3 |  SI2324DS-T1-E3 |  SI2324DS-T1-GE3 |
|  SI2324DS-T1-GE3 |  SI2325DS-T1-E3 |  SI2325DS-T1-E3 |  SI2325DS-T1-GE3 |  SI2325DS-T1-GE3 |
|  SI2327DS-T1-E3 |  SI2327DS-T1-E3 |  SI2327DS-T1-GE3 |  SI2327DS-T1-GE3 |  SI2328DS |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited